## NSN 5961-01-309-7442

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-309-7442 **Overall Length:** 1.187 inches **Overall Height:** 0.562 inches **End Application:** Electronic assembly, warhead **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case and burn in **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 70.0 emitter to base voltage, dc and 160.0 collector to base voltage, dc **Current Rating Per Characteristic:** Between 4.00 amperes source cutoff current and 16.00 amperes source cutoff current **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 40.0 static forward current transfer ratio, common-emitter and 80.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 flange Shelf Life: N/a **Unit Of Measure: Demilitarization:**